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AFF'S PCT/JP99/05787
     ANSWER 1 OF 1 HCAPLUS COPYRIGHT 2003 ACS
L1
     2000:278028 HCAPLUS
ΑN
     132:309402
DN
     Flame-retardant epoxy resin encapsulation compositions and semiconductor
ΤI
     devices made using the same
     Kiuchi, Yukihiro; Iji, Masatoshi; Terajima, Katsushi; Katayama, Isao;
IN
     Matsui, Yasuo; Oota, Ken
PΑ
     Nec Corp., Japan; Sumitomo Bakelite Co. Ltd.
     PCT Int. Appl., 40 pp.
SO
     CODEN: PIXXD2
DT
     Patent
     Japanese
LA
IC
     ICM C08G059-62
     ICS C08L063-00; C08K003-00; H01L023-29
CC
     38-3 (Plastics Fabrication and Uses)
FAN.CNT 1
     PATENT NO.
                     KIND DATE
                                          APPLICATION NO. DATE
                                          ______
PΤ
     WO 2000023494
                     A1
                           20000427
                                          WO 1999-JP5787 19991020
        W: KR, SG, US
         RW: AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL,
             PT, SE
     JP 2000129092
                           20000509
                                           JP 1998-299606
                      Α2
                                                           19981021
     EP 1142923
                      A1
                            20011010
                                          EP 1999-949323
                                                           19991020 <--
        R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,
             IE, FI
PRAI JP 1998-299606
                      Α
                           19981021
     WO 1999-JP5787
                            19991020
                      W
                                     <--
     The compns. comprise an epoxy resin (A), a phenolic resin (B), an inorg.
AB
     filler (C), and a curing accelerator (D) and give cured products with
     flexural modulus (E; in kg/mm2) at 240.degree. provided that
     0.015W+4.1.ltoreq.E.ltoreq.0.27W+21.8 when 30.ltoreq.W<60 (W = the content
     of the filler C in %) and 0.30W-13.ltoreq.E.ltoreq.3.7W-184 when
     60.ltoreq.W.ltoreq.95. The cured compns. form foamed layers upon
     pyrolysis and firing to thereby have good flame retardancy. Thus,
     kneading a compn. comprising 4,4'-biphenyl diglycidyl ether/3,3',5,5'-
     tetramethylbiphenyl diglycidyl ether mixed resin 16.58, a
     phenol-biphenylaralkyl resin 20.23, fused crushed silica 60.0, carnauba
     wax 0.51, triphenylphosphine 0.40, a silane coupler 1.57 and carbon black
     0.75% at 100.degree. for .apprx.5 min, cooling, crushing, pelletizing,
     transfer molding and post curing at 175.degree. for 4 h gave test pieces
     with 240.degree.-flexural modulus 28.0 kg/mm2 and UL94 flammability rating
ST
     fire resistance electronic packaging epoxy resin compn; encapsulation
     electronic epoxy phenolic resin compn; silica filler epoxy phenolic resin
     electronic packaging
IT
     Epoxy resins, uses
     RL: POF (Polymer in formulation); PRP (Properties); TEM (Technical or
     engineered material use); USES (Uses)
        (OH-contg. polybenzyl-based; flame-retardant epoxy resin encapsulation
        compns. and semiconductor devices made using same)
IT
     Electronic packaging materials
     Semiconductor devices
        (flame-retardant epoxy resin encapsulation compns. and semiconductor
        devices made using same)
IT
     Polybenzyls
     RL: POF (Polymer in formulation); PRP (Properties); TEM (Technical or
     engineered material use); USES (Uses)
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(hydroxy-contg., epoxidized; flame-retardant epoxy resin encapsulation compns. and semiconductor devices made using same)

IT 178965-58-7D, glycidyl ethers 192333-07-6D, glycidyl ethers RL: POF (Polymer in formulation); PRP (Properties); TEM (Technical or engineered material use); USES (Uses)

(base resins; flame-retardant epoxy resin encapsulation compns. and semiconductor devices made using same)

IT 2461-46-3, 4,4'-Biphenyl diglycidyl ether 27043-37-4 85954-11-6, 3,3',5,5'-Tetramethylbiphenol diglycidyl ether

RL: PRP (Properties); TEM (Technical or engineered material use); USES (Uses)

(base resins; flame-retardant epoxy resin encapsulation compns. and semiconductor devices made using same)

IT 603-35-0, Triphenylphosphine, uses

RL: CAT (Catalyst use); USES (Uses)

(curing accelerator; flame-retardant epoxy resin encapsulation compns. and semiconductor devices made using same)

IT 178965-58-7 192333-07-6

RL: MOA (Modifier or additive use); USES (Uses)

(curing agent; flame-retardant epoxy resin encapsulation compns. and semiconductor devices made using same)

IT 7631-86-9, Silica, uses

RL: MOA (Modifier or additive use); USES (Uses)

(fillers; flame-retardant epoxy resin encapsulation compns. and semiconductor devices made using same)

RE.CNT 3 THERE ARE 3 CITED REFERENCES AVAILABLE FOR THIS RECORD RE

- (1) Sumitomo Bakelite Company Limited; JP 07238141 A 1995 HCAPLUS
- (2) Toshiba Chemical Corporation; JP 08245754 A 1996 HCAPLUS
- (3) Yuka Shell Epoxy K K; JP 08253551 A 1996 HCAPLUS

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AVE REQUESTED DATA FROM FILE 'HCAPLUS' - CONTINUE? (Y) /N:end
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             1 603-35-0/BI
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             1 7631-86-9/BI
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L2
               BI OR 603-35-0/BI OR 7631-86-9/BI OR 85954-11-6/BI)
=> d scan
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HOW MANY MORE ANSWERS DO YOU WISH TO SCAN? (1):6

L2 7 ANSWERS REGISTRY COPYRIGHT 2003 ACS
IN Poly[(hydroxyphenylene)methylene-1,4-phenylenemethylene] (9CI)
MF (C14 H12 O)n
CI IDS, PMS, COM, MAN

\*\*RELATED POLYMERS AVAILABLE WITH POLYLINK\*\*

KATHLEEN FULLER EIC 1700/PARKER LAW 308-4290

\*\*\* STRUCTURE DIAGRAM IS NOT AVAILABLE \*\*\*

L2 7 ANSWERS REGISTRY COPYRIGHT 2003 ACS

IN Phosphine, triphenyl- (7CI, 8CI, 9CI)

MF C18 H15 P

CI COM

\*\*PROPERTY DATA AVAILABLE IN THE 'PROP' FORMAT\*\*

L2 7 ANSWERS REGISTRY COPYRIGHT 2003 ACS IN Silica (6CI, 7CI, 8CI, 9CI) ADDITIONAL NAMES NOT AVAILABLE IN THIS FORMAT MF O2 Si CI COM

o = si = o

\*\*PROPERTY DATA AVAILABLE IN THE 'PROP' FORMAT\*\*

L2 7 ANSWERS REGISTRY COPYRIGHT 2003 ACS

IN Oxirane, 2,2'-[(3,3',5,5'-tetramethyl[1,1'-biphenyl]-4,4'diyl)bis(oxymethylene)]bis- (9CI)

MF C22 H26 O4

CI COM

\*\*PROPERTY DATA AVAILABLE IN THE 'PROP' FORMAT\*\*

L2 7 ANSWERS REGISTRY COPYRIGHT 2003 ACS

IN Poly[[1,1'-biphenyl]-4,4'-diylmethylene(hydroxyphenylene)methylene] (9CI)

MF (C20 H16 O)n

CI IDS, PMS, MAN

\*\*RELATED POLYMERS AVAILABLE WITH POLYLINK\*\*

\*\*\* STRUCTURE DIAGRAM IS NOT AVAILABLE \*\*\*

KATHLEEN FULLER EIC 1700/PARKER LAW 308-4290

L2 7 ANSWERS REGISTRY COPYRIGHT 2003 ACS
IN Oxirane, 2,2'-[[1,1'-biphenyl]-4,4'-diylbis(oxymethylene)]bis- (9CI)
MF C18 H18 O4
CI COM

\*\*PROPERTY DATA AVAILABLE IN THE 'PROP' FORMAT\*\*

ALL ANSWERS HAVE BEEN SCANNED

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